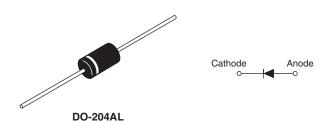
**Vishay Semiconductors** 

### Schottky Rectifier, 1.1 A



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PRODUCT SUMMARY					
Package	DO-204AL (DO-41)				
I <sub>F(AV)</sub>	1.1 A				
V <sub>R</sub>	50 V, 60 V				
V <sub>F</sub> at I <sub>F</sub>	See Electrical table				
I <sub>RM</sub> max.	11.0 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Single die				
E <sub>AS</sub>	2.0 mJ				

### FEATURES

- Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



**FREE** Available

- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- · Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

#### DESCRIPTION

The VS-11DQ... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	Rectangular waveform	1.1	A				
V <sub>RRM</sub>		50/60	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	150	А				
V <sub>F</sub>	1 Apk, T <sub>J</sub> = 125 °C	0.53	V				
TJ	Range	- 40 to 150	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-11DQ05	VS-11DQ05-M3	VS-11DQ06	VS-11DQ06-M3	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	50	50	60	60	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	50	50	00	00	v	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS			
Maximum average forward current See fig. 4	I <sub>F(AV)</sub>	50 % duty cycle at $T_{C}$ = 84 °C, rectangular waveform		1.1			
Maximum peak one cycle non-repetitive surge current	1	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with	150	А		
See fig. 6		10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	25			
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 4 mH		2.0	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 1.0		1.0	А		

Revision: 21-Sep-11

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			
	V <sub>FM</sub> <sup>(1)</sup>	1 A	T <sub>1</sub> = 25 °C	0.58	V	
Maximum forward voltage drop See fig. 1		2 A	1j=25 C	0.76		
		1 A	T <sub>1</sub> = 125 °C	0.53		
		2 A	1j = 125 C	0.64		
Maximum reverse leakage current	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		1.0	mA	
See fig. 2	IRM (')	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	11		
Typical junction capacitance	C <sub>T</sub>	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		55	pF	
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µ			V/µs	

#### Note

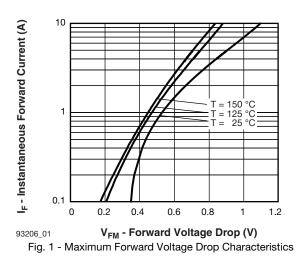
 $^{(1)}\,$  Pulse width < 300  $\mu s,\,duty\,cycle$  < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 40 to 150	°C		
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation Without cooling fin	100	°C/W		
Typical thermal resistance, junction to lead	R <sub>thJL</sub>	DC operation See fig. 4	81	0/14		
Approvimete weight			0.33	g		
Approximate weight			0.012	oz.		
Marking device			11DQ05			
		Case style DO-204AL (DO-41)		Q06		

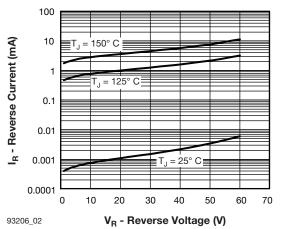
#### Note

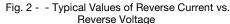
(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

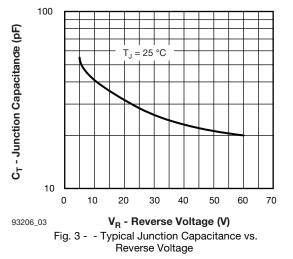
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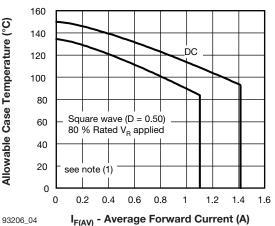


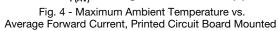
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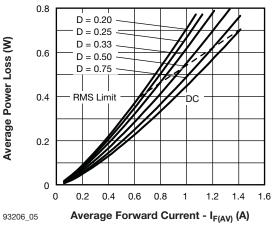




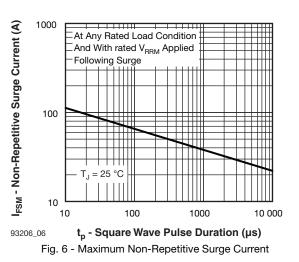












Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6);  $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

Revision: 21-Sep-11

3

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#### **ORDERING INFORMATION TABLE**

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VISHA

								1
Device code	VS-	11	D	Q	06	TR	-M3	
		2	3	4	5	6	7	1
	1 -	Visł	nay Sem	niconduc	tors pro	duct		
	2 -	11 =	= 1.1 A (	axial an	d small	packag	es - cur	rrent is x 10)
	3 -	D =	DO-41	package	9			
	4 -	Q =	Schottk	xy Q se	ries		Г	
	5 -	06 =	= Voltag	e ratings	s ——			05 = 50 V 06 = 60 V
	6 -	TR	= Tape	and reel	packag	е	L	
		Nor	ie = Bull	k packa	ge			
	7 -	Env	ironmer	ntal digit				
		• N	one = Le	ead (Pb)	-free an	d RoHS	S compl	iant
		• -N	13 = Hal	ogen-fre	e, RoH	S comp	liant, ar	nd terminations lead (Pb

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-11DQ05	1000	1000	Bulk			
VS-11DQ05TR	5000	5000	Tape and reel			
VS-11DQ05-M3	1000	1000	Bulk			
VS-11DQ05TR-M3	5000	5000	Tape and reel			
VS-11DQ06	1000	1000	Bulk			
VS-11DQ06TR	5000	5000	Tape and reel			
VS-11DQ06-M3	1000	1000	Bulk			
VS-11DQ06TR-M3	5000	5000	Tape and reel			

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95241					
Part marking information	www.vishay.com/doc?95304				
Packaging information	www.vishay.com/doc?95338				

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27.0 (1.06) MIN. (2 places)

1.27 (0.050) MAX.

Flash (2 places)

2.70 (0.106)

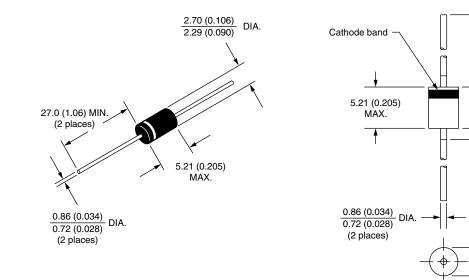
2.29 (0.090)

DIA.



Axial DO-204AL (DO-41)

#### **DIMENSIONS** in millimeters (inches)





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